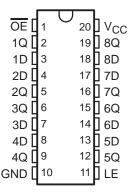
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- **Controlled Baseline**
 - One Assembly/Test Site, One Fabrication
- **Enhanced Diminishing Manufacturing** Sources (DMS) Support
- **Enhanced Product-Change Notification**
- Qualification Pedigree[†]
- **Supports Mixed-Mode Signal Operation** (5-V Input and Output Voltages With 3.3-V V_{CC})
- **Typical V_{OLP} (Output Ground Bounce)** <0.8 V at V_{CC} = 3.3 V, T_A = 25°C
- **Supports Unregulated Battery Operation** Down to 2.7 V
- Ioff and Power-Up 3-State Support Hot Insertion
- † Component qualification in accordance with JEDEC and industry standards to ensure reliable operation over an extended temperature range. This includes, but is not limited to, Highly Accelerated Stress Test (HAST) or biased 85/85, temperature cycle, autoclave or unbiased HAST, electromigration, bond intermetallic life, and mold compound life. Such qualification testing should not be viewed as justifying use of this component beyond specified performance and environmental limits.

- Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors
- Latch-Up Performance Exceeds 500 mA Per JESD 17
- **ESD Protection Exceeds JESD 22**
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)





description/ordering information

This octal latch is designed specifically for low-voltage (3.3-V) V_{CC} operation, but with the capability to provide a TTL interface to a 5-V system environment.

While the latch-enable (LE) input is high, the Q outputs follow the data (D) inputs. When LE is taken low, the Q outputs are latched at the logic levels set up at the D inputs.

A buffered output-enable (OE) input can be used to place the eight outputs in either a normal logic state (high or low logic levels) or the high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and increased drive provide the capability to drive bus lines without need for interface or pullup components.

OE does not affect the internal operations of the latches. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

When V_{CC} is between 0 and 1.5 V, the devices are in the high-impedance state during power up or power down. However, to ensure the high-impedance state above 1.5 V, $\overline{\text{OE}}$ should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

Active bus-hold circuitry holds unused or undriven inputs at a valid logic state. Use of pullup or pulldown resistors with the bus-hold circuitry is not recommended.

This device is fully specified for hot-insertion applications using Ioff and power-up 3-state. The Ioff circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down. The power-up 3-state circuitry places the outputs in the high-impedance state during power up and power down, which prevents driver conflict.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



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ORDERING INFORMATION

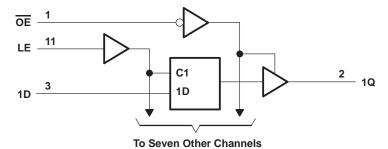
TA	PACK	PACKAGE†	ORDERABLE PART NUMBER	TOP-SIDE MARKING
-40°C to 85°C	TSSOP - PW	Tape and reel	SN74LVTH373IPWREP	LH373EP

[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

FUNCTION TABLE (each latch)

	INPUTS		OUTPUT
OE	LE	D	Q
L	Н	Н	Н
L	Н	L	L
L	L	Χ	Q_0
Н	X	Χ	Z

logic diagram (positive logic)



SN74LVTH373-EP 3.3-V ABT OCTAL TRANSPARENT D-TYPE LATCH WITH 3-STATE OUTPUTS

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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC}	
Input voltage range, V _I (see Note 1)	0.5 V to 7 V
Voltage range applied to any output in the high-impedance	
or power-off state, V _O (see Note 1)	
Voltage range applied to any output in the high state, V _O (see Note 1)	
Current into any output in the low state, IO	128 mA
Current into any output in the high state, IO (see Note 2)	64 mA
Input clamp current, I _{IK} (V _I < 0)	
Output clamp current, I _{OK} (V _O < 0)	
Package thermal impedance, θ _{JA} (see Note 3)	
Storage temperature range, T _{stg}	

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

- 2. This current flows only when the output is in the high state and $V_O > V_{CC}$.
- 3. The package thermal impedance is calculated in accordance with JESD 51-7.

recommended operating conditions (see Note 4)

			MIN	MAX	UNIT
Vcc	Supply voltage		2.7	3.6	V
VIH	High-level input voltage		2		V
V _{IL}	Low-level input voltage			8.0	V
VI	Input voltage			5.5	V
IOH	High-level output current			-32	mA
loL	Low-level output current			64	mA
Δt/Δν	Input transition rise or fall rate	Outputs enabled		10	ns/V
Δt/ΔV _{CC}	Power-up ramp rate	_	200		μs/V
TA	Operating free-air temperature	_	-40	85	°C

NOTE 4: All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



SN74LVTH373-EP 3.3-V ABT OCTAL TRANSPARENT D-TYPE LATCH WITH 3-STATE OUTPUTS

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIO	NS	MIN	TYP†	MAX	UNIT	
VIK		V _{CC} = 2.7 V,			-1.2	V		
		V _{CC} = 2.7 V to 3.6 V,	I _{OH} = -100 μA	V _{CC} -0.2				
VOH		$V_{CC} = 2.7 \text{ V},$	$I_{OH} = -8 \text{ mA}$	2.4			V	
		V _{CC} = 3 V	$I_{OH} = -32 \text{ mA}$	2				
		V 0.7.V	I _{OL} = 100 μA			0.2		
		V _{CC} = 2.7 V	I _{OL} = 24 mA			0.5		
VOL			I _{OL} = 16 mA			0.4	V	
		V _{CC} = 3 V	$I_{OL} = 32 \text{ mA}$			0.5		
			$I_{OL} = 64 \text{ mA}$			0.55		
		$V_{CC} = 0 \text{ or } 3.6 \text{ V},$	$V_{I} = 5.5 V$			10		
l _i	Control inputs	V _{CC} = 3.6 V,	$V_I = V_{CC}$ or GND			±1	μА	
Data	Data		VI = VCC			1		
	inputs	V _{CC} = 3.6 V	V _I = 0					
l _{off}		$V_{CC} = 0$,	V_I or $V_O = 0$ to 4.5 V			±100	μΑ	
		V 2V	V _I = 0.8 V	75				
li/halab	Data	V _{CC} = 3 V	V _I = 2 V	-75			μΑ	
I(hold)	inputs	V _{CC} = 3.6 V [‡] ,	$V_I = 0$ to 3.6 V			500 -750	μΑ	
lozh		V _{CC} = 3.6 V,	VO = 3 V			5	μΑ	
lozL		V _{CC} = 3.6 V,	V _O = 0.5 V			-5	μΑ	
lozpu		$V_{CC} = 0 \text{ to } 1.5 \text{ V}, V_{O} = 0.5 \text{ V to } 3 \text{ V}, \overline{OE} = \text{don}$	't care			±100	μΑ	
lozpd		$V_{CC} = 1.5 \text{ V to } 0, V_{O} = 0.5 \text{ V to } 3 \text{ V}, \overline{OE} = \text{dor}$	't care			±100	μΑ	
			Outputs high			0.19		
ICC		$V_{CC} = 3.6 \text{ V}, I_{O} = 0, V_{I} = V_{CC} \text{ or GND}$	Outputs low	5		mA		
			Outputs disabled			0.19	<u> </u>	
∆lcc§		$V_{CC} = 3 \text{ V to } 3.6 \text{ V}$, One input at $V_{CC} - 0.6 \text{ V}$,	V_{CC} = 3 V to 3.6 V, One input at V_{CC} – 0.6 V, Other inputs at V_{CC} or GND				mA	
Ci		V _I = 3 V or 0			3		pF	
Co		V _O = 3 V or 0	· ·					

[†] All typical values are at $V_{CC} = 3.3 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

timing requirements over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

		V _{CC} =	3.3 V 3 V	VCC =	2.7 V	UNIT
		MIN	MAX	MIN	MAX	
t _W	Pulse duration, LE high	3		3		ns
t _{su}	Setup time, data before LE↓	1.1		0.4		ns
th	Hold time, data after LE↓	1.4	•	1.4		ns



[‡] This is the bus-hold maximum dynamic current. It is the minimum overdrive current required to switch the input from one state to another.

[§] This is the increase in supply current for each input that is at the specified TTL voltage level, rather than VCC or GND.

SN74LVTH373-EP 3.3-V ABT OCTAL TRANSPARENT D-TYPE LATCH WITH 3-STATE OUTPUTS SCBS770 - NOVEMBER 2003

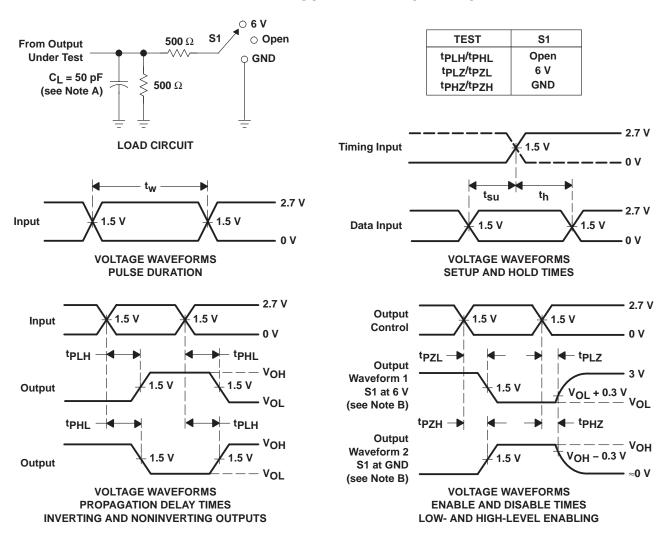
switching characteristics over recommended free-air temperature, C_L = 50 pF (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	TO	Vo	± 0.3 V	V	V _{CC} =	UNIT	
	(INPUT)	(OUTPUT)	MIN	TYP	MAX	MIN	MAX	
tPLH .	2	•	1.5	2.6	3.9		4.5	
t _{PHL}	D	Q	1.5	2.6	3.9		4.5	ns
^t PLH		•	1.7	2.7	4.2		4.9	
^t PHL	LE	Q	1.7	2.7	4.2		4.9	ns
^t PZH	ŌĒ	•	1.3	3	4.8		5.9	
t _{PZL}	OE	Q	1.3	3	4.8		5.5	ns
^t PHZ	ŌĒ	•	1.9	3	4.6		4.9	
tPLZ	OE .	Q	1.9	3	4.5		4.6	ns

 $^{^{\}dagger}$ All typical values are at VCC = 3.3 V, TA = 25°C.

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PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_Q = 50 \ \Omega$, $t_f \leq$ 2.5 ns, $t_f \leq$ 2.5 ns.
- D. The outputs are measured one at a time with one transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms



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PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
SN74LVTH373IPWREP	Active	Production	TSSOP (PW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LH373EP
V62/04675-01XE	Active	Production	TSSOP (PW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LH373EP

⁽¹⁾ Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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OTHER QUALIFIED VERSIONS OF SN74LVTH373-EP:

Catalog: SN74LVTH373

⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

PACKAGE OPTION ADDENDUM

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Military: SN54LVTH373

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	•	•	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVTH373	IPWREP	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1

PACKAGE MATERIALS INFORMATION

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*All dimensions are nominal

Device	Device Package Type		Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
SN74LVTH373IPWREP	TSSOP	PW	20	2000	353.0	353.0	32.0	

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